ZOWIE

Schottky Barrier Diode

(60V / 8A)

Z3PK860H

FEATURES

* Halogen-free type
* Lead free product, compliance to RoHS
* Lead less chip form, no lead damage
* Low power loss, High efficiency
* High current capability, low VF
* Plastic package has Underwriters Laboratory Flammability Classification 94V-0
* Patented ZPAK™ Package Technology

APPLICATION

* Switching mode power supply applications
* Portable equipment battery applications
* High frequency rectification
* DC / DC Converter
* Designed as bypass diodes for solar panels

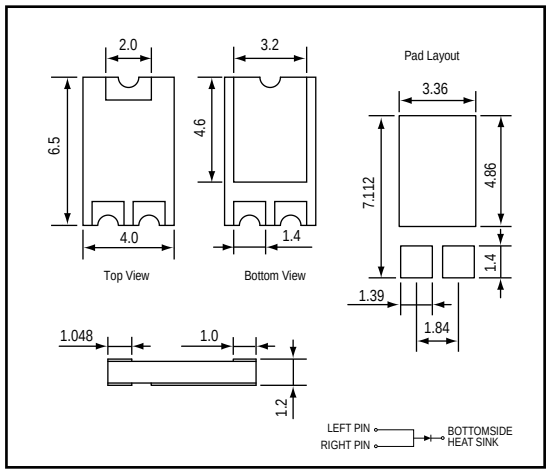
MECHANICAL DATA

Case : Packed with FRP substrate and epoxy underfilled
Terminals : Pure Tin plated (Lead-Free), solderable per MIL-STD-750, Method 2026.

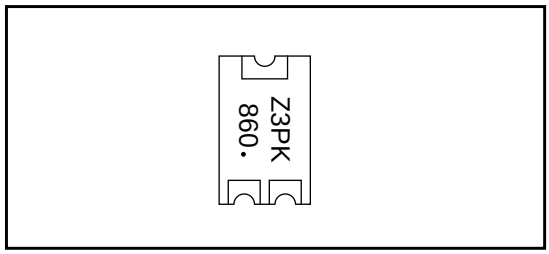
OUTLINE DIMENSIONS

Case : Z3PAK

Unit : mm



MARKING



Absolute Maximum Ratings (Ta = 25 °C)

ITEM	Symbol	Conditions	Rating	Unit
			Z3PK860H	
Repetitive peak reverse voltage	V_{RRM}		60	V
Average forward current	$I_{F(AV)}$		8	A
Peak forward surge current	I_{FSM}	8.3ms single half sine-wave	180	A
Operating junction temperature Range	T_j		-55 to +150	°C
Storage temperature Range	T_{STG}		-55 to +150	°C

Electrical characteristics (Ta = 25 °C)

ITEM	Symbol	Conditions	Min.	Typ.	Max.	Unit
Forward voltage (NOTE 1)	V_F	I_F = 8A	-	0.63	0.70	V
Repetitive peak reverse current	I_{RRM}	V_R = Max. V_{RRM} Ta = 25 °C	-	0.01	0.10	mA
		Ta = 125 °C	-	-	50	
Thermal resistance	$R_{th(JA)}$	Junction to ambient (NOTE 2)	-	60	-	°C/W
	$R_{th(JL)}$	Junction to lead (NOTE 2)	-	22	-	°C/W
	$R_{th(JC)}$	Junction to case (NOTE 2)	-	20	-	°C/W

NOTES : (1) Pulse test width PW=300usec , 1% duty cycle.
(2) Mounted on P.C.B. with 14 x 14mm copper pad areas.

FIG.1 - FORWARD CURRENT DERATING CURVE

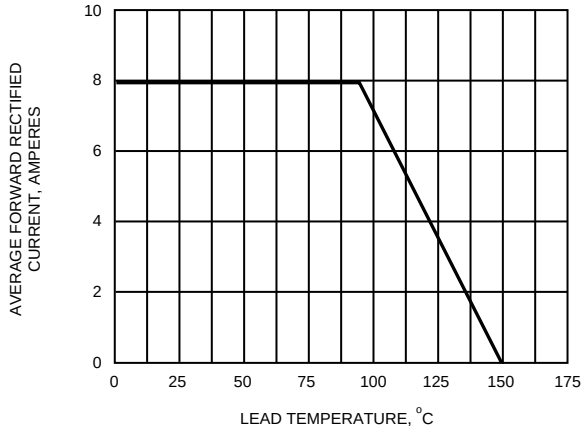


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

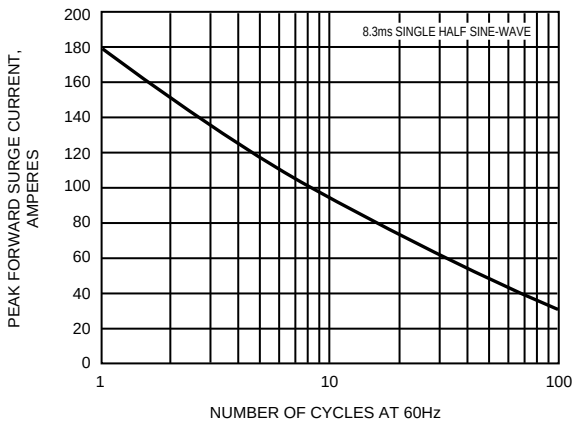


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

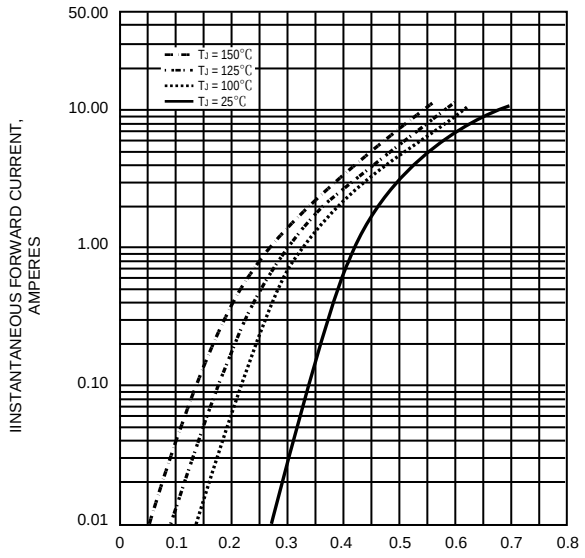


FIG.4 - TYPICAL REVERSE CHARACTERISTICS